## NSN 5961-01-065-8080

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View Online at https://aerobasegroup.com/nsn/5961-01-065-8080 **Inclosure Material:** Metal **Overall Length:** Between 0.874 inches and 1.030 inches Overall Diameter: Between 0.840 inches and 0.910 inches **Mounting Facility Quantity: Internal Configuration:** Junction contact **Mounting Method:** Threaded stud Thread Size: 0.500 inches **Semiconductor Material:** Silicon **Voltage Rating In Volts Per Characteristic:** 600.0 repetitive peak off-state voltage and 600.0 repetitive peak reverse voltage and 720.0 nonrepetitive peak reverse voltage **Current Rating Per Characteristic:** 110.00 amperes forward current, total rms horsepower metric **Power Rating Per Characteristic:** 2.0 watts small-signal input power, common-collector peak **Maximum Operating Tempurature Per Measurement Point:** 125.0 degrees celsius junction **Special Features:** Junction pattern arrangement: pnpn **Thread Series Designator:** Unf **Terminal Type And Quantity:** 2 tab, solder lug and 1 threaded stud Shelf Life: N/a **Unit Of Measure: Demilitarization:** No Fiig: A110a0